

Graphenes now go monolayer and single crystalline

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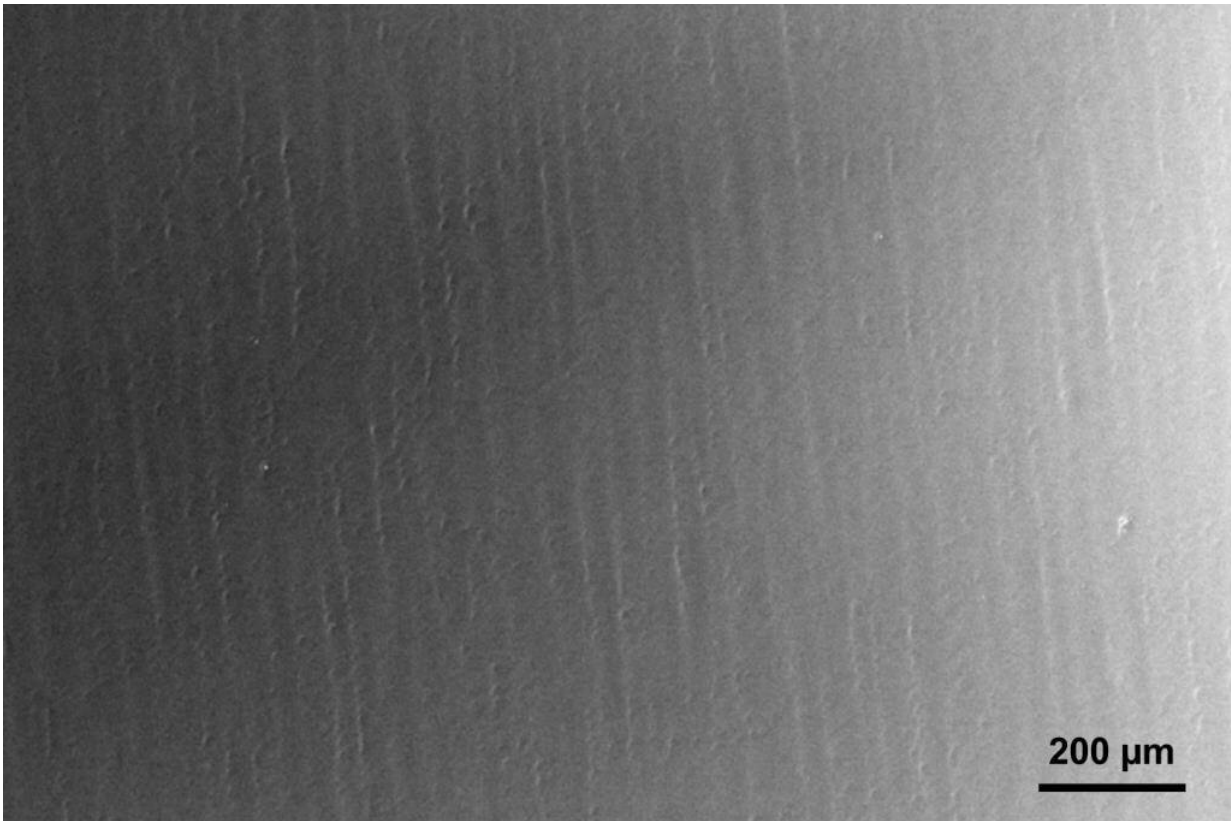


Figure 1 A large scale (~2.5 mm x 1.6 mm) SEM image of an adlayer-free single crystal graphene film on a Cu(111) foil. Credit: Institute for Basic Science

IBS-CMCM scientists have reported a truly single layer (i.e., adlayer-free) large area graphene film on large area copper foils. They refined

the chemical vapor deposition (CVD) growth method by eliminating all carbon impurities inside the copper foils on which graphene is grown. This uniform, "perfect" single layer, single crystal graphene is expected to find use as an ultrathin support material for high-resolution transmission electron microscopy imaging, and in optical devices. Also as an appropriate graphene to achieve extremely uniform functionalization which leads to many other applications, particularly for sensors of various types.

Director Rodney Ruoff's research group from the Center for Multidimensional Carbon Materials (CMCM) within the Institute for Basic Science (IBS) at the Ulsan National Institute of Science and Technology (UNIST) has reported a truly single [layer](#) (i.e., adlayer-free) large area graphene film on large area copper foils. This might seem like the latest in a series of seemingly similar declarations on single layer graphene. However, this achievement differs from other thousands of previous publications in that none of them had described truly single layer graphene over large area. Adlayers (bilayer or multilayer regions) have always been present in such [films](#).

IBS scientists refined the [chemical vapor deposition](#) (CVD) growth method by eliminating all carbon impurities inside the copper foils on which graphene is grown. CVD on metal foils (especially copper foils) is currently the most promising route for scalable and reproducible synthesis of large-area graphene films of high quality. The team investigated why "adlayers" appeared in the graphene film grown on copper foils and found that the carbon impurities inside the foil directly lead to the nucleation and growth of adlayers. (Adlayers are regions in the film where there are 2 layers or 3 layers present—multilayer "patches," that is.)

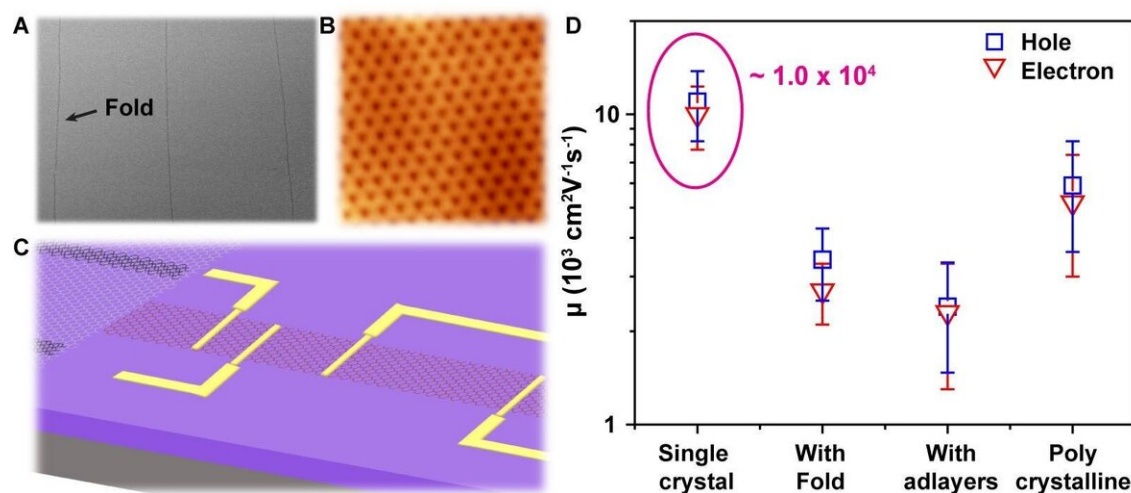


Figure 2 (A) SEM image of an adlayer-free single crystal graphene film with parallel long folds on a Cu(111) foil. (B) A high-resolution ultra-high-vacuum STM image of the honeycomb lattice of the single crystal graphene film. (C) Schematic illustration for straightforward fabrication of high-performance field-effect transistors in the region lying between two adjacent folds in the single crystal graphene film. (D) Carrier mobilities measured from field-effect transistors patterned with various kinds of graphene samples; adlayer-free single crystal graphene film shows the best performance. Credit: Institute for Basic Science

"We discovered that the commercial copper foils have 'excess carbon' particularly near the surface—to a depth of about 300 nm, by using time-of-flight secondary ion mass spectrometry and combustion analysis. From a discussion with one technical expert in Jiangxi Copper Corporation Limited, one of the world's largest suppliers of copper foils, we learned that the carbon is embedded in the copper foil during manufacture, probably from hydrocarbon-based oil(s) used to lubricate rollers that the [copper](#) foil contacts at the high rolling temperatures," said Dr. Da Luo, first author of the article. After completely removing this

carbon by annealing under H₂ at 1060 degrees Celsius, they were able to achieve adlayer-free and thus truly single layer graphene film.

By applying the same method, the IBS scientists also obtained an adlayer-free single layer and single crystal graphene film on a single crystal Cu [foil](#). One of the first authors Meihui Wang explained, "We thus solved two problems that have persistently been present in prior syntheses of CVD graphene films (adlayers and grain boundaries (GBs)) at one time." Indeed, achieving perfect uniformity in the number of layers over a large area (single or double layers, for example) can be used to ensure a consistent device performance. Adlayer regions differ in, e.g., density and size when present in the active regions of devices. In addition to adlayers, GBs are present in polycrystalline graphene films prepared by CVD where graphene islands with different crystallographic orientations join to complete the film. The presence of GBs lowers carrier mobility and thermal conductivity, and reduces the mechanical strength.

Still, the scientists were left with one fascinating feature in their single crystal films: This single crystal graphene contains highly oriented parallel "folds" that are centimeters in length, roughly a hundred nanometers in width, and separated by 20 to 50 micrometers. Just like adlayers and GBs, folds were observed to significantly decrease the carrier mobility of graphene. To eliminate such scattering effects of adlayers, GBs and folds, the team patterned [field-effect transistors](#) in the region lying between two adjacent folds and with the transistors parallel to the folds. Unlike folds distributed quasi-randomly in the polycrystalline graphene film, the folds are highly aligned in the large area single crystal graphene film. This makes it easy to fabricate integrated high performance devices from the regions between the folds. Wang explained, "The region between two adjacent folds is 'clean' without any folds, adlayers, or GBs. This enabled the device to have very high electron and hole mobility. The field-effect transistors show very high room temperature carrier mobility values of around 1.0×10^4

$\text{cm}^2\text{V}^{-1}\text{s}^{-1}$. Such high carrier mobility "translates" to various useful devices having high performance."

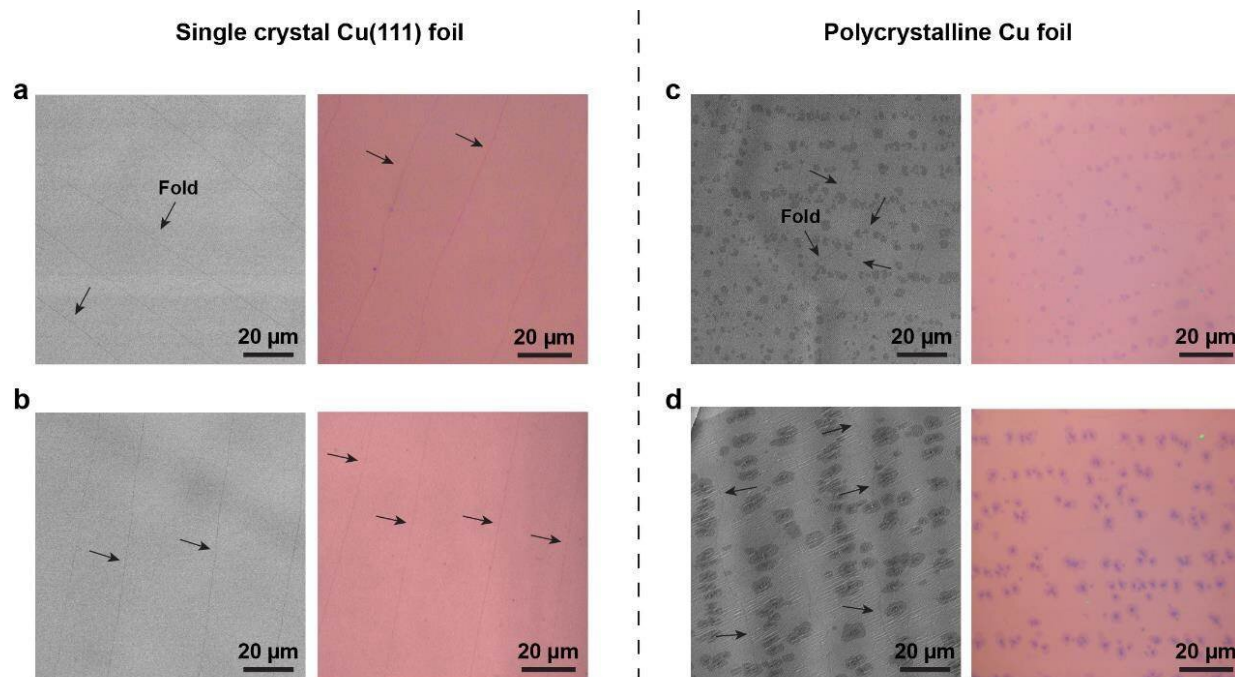


Figure 3 (a-b) (left panel) SEM images of adlayer-free single crystal graphene films on Cu(111) foils and (right panel) optical images of the films after transfer to 300 nm SiO₂/Si wafers. (c-d) (left panel) SEM images of polycrystalline graphene films with adlayers on polycrystalline Cu foils and (right panel) optical images of the films after transfer to 300 nm SiO₂/Si wafers. CVD parameters for gas flow and pressure were as follows: (a, c) H₂/CH₄ (200 sccm / 1 sccm) at 2.0 Torr; (b, d) H₂/CH₄ (30 sccm / 30 sccm 0.1% CH₄ in Ar) at 30.0 Torr. The black arrows point to folds. Credit: Institute for Basic Science

Director Ruoff noted, "Our approach towards large area adlayer-free single crystal graphene is a breakthrough. This uniform, 'perfect' single layer, single crystal graphene is expected to find use as an ultrathin support material for high-resolution transmission electron microscopy

imaging, and in optical devices. Also as an appropriate [graphene](#) to achieve extremely uniform functionalization which leads to many other applications, particularly for sensors of various types. I also would like to note that we greatly valued the strong contributions by coauthors from UNIST, from HKUST, and from SKKU." This research was supported by the Institute for Basic Science, and has been published in the journal *Advanced Materials*.

More information: Da Luo et al. Adlayer-Free Large-Area Single Crystal Graphene Grown on a Cu(111) Foil. *Advanced Materials*. DOI: [10.1002/adma.201903615](https://doi.org/10.1002/adma.201903615)

Provided by Institute for Basic Science

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